TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74VHC139F, TC74VHC139FN, TC74VHC139FT

#### **DUAL 2-TO-4 LINE DECODER**

The TC74VHC139 is an advanced high speed CMOS 2 to 4 LINE DECODER/DEMULTIPLEXER fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The active low enable input can be used for gating or it can be used as a data input for demultiplexing applications.

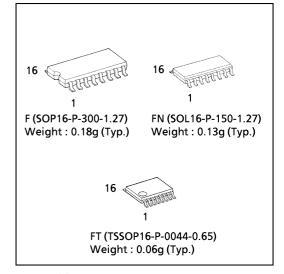
When the enable input is held High, all four outputs are fixed at a high logic level independent of the other inputs.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

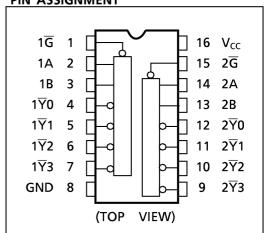
#### FEATURES:

- High Speed······ $t_{pd} = 5.0$ ns(typ.) at  $V_{CC} = 5V$
- Low Power Dissipation ·············  $I_{CC} = 4\mu A(Max.)$  at  $Ta = 25^{\circ}C$
- High Noise Immunity  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays ····· t<sub>pLH</sub> ≃ t<sub>pHL</sub>
- Wide Operating Voltage Range ···· V<sub>CC</sub> (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74ALS139

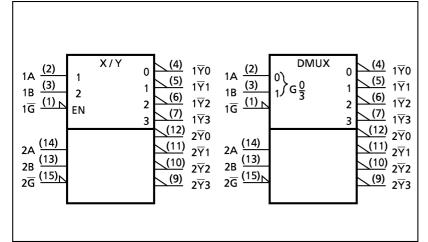
(Note) The JEDEC SOP (FN) is not available in Japan.



#### **PIN ASSIGNMENT**



#### **IEC LOGIC SYMBOL**

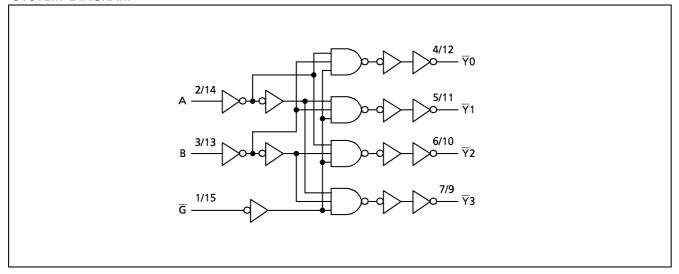


INPUTS			C	UT					
ENABLE	SELECT		<u></u> 70	<u>7</u> 1	<u></u> <u></u> <u></u> <u></u> <u></u> <u></u> <u></u> <u></u> <u> </u> <u> </u>	<u></u> 73	SELECTED OUTPUT		
G	В	Α		1 1	12	13	001701		
Н	Х	Х	Н	Н	Н	Н	NONE		
L	L	L	L	Н	Н	Η	<u></u> 70		
L	L	Н	Н	L	Н	Н	<u>¥</u> 1		
L	Н	L	Η	Н	L	Н	₹2		
L	Н	Н	Н	Н	Н	L	<u></u> 73		

X : Don't Care

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# SYSTEM DIAGRAM



# **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{cc}$	-0.5~7.0	V
DC Input Voltage	VIN	<b>−</b> 0.5~7.0	V
DC Output Voltage	V <sub>OUT</sub>	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I <sub>IK</sub>	<b>-20</b>	mA
Output Diode Current	I <sub>OK</sub>	± 20	mA
DC Output Current	I <sub>OUT</sub>	± 25	mA
DC V <sub>CC</sub> /Ground Current	I <sub>cc</sub>	± 75	mA
Power Dissipation	P <sub>D</sub>	180	mW
Storage Temperature	T <sub>stg</sub>	<b>−65~150</b>	°C

# **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{cc}$	2.0~5.5	<b>V</b>
Input Voltage	VIN	0~5.5	٧
Output Voltage	V <sub>OUT</sub>	0~V <sub>cc</sub>	<b>&gt;</b>
Operating Temperature	T <sub>opr</sub>	<b>−40~85</b>	°C
Input Rise and Fall Time	dt/dv	$0\sim100 \ (V_{CC} = 3.3 \pm 0.3 V)$ $0\sim20 \ (V_{CC} = 5 \pm 0.5 V)$	ns / V

#### DC ELECTRICAL CHARACTERISTICS

PARAMETER	CVM/IDOL	TEST CONDITION		V <sub>cc</sub>	Ta = 25°C		С	Ta = −40~85°C		UNIT
FARAIVIETER	SYMBOL	1231 CC	(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT	
High - Level	.,			2.0	1.50	_	_	1.50	_	
Input Voltage	V <sub>IH</sub>			3.0~ 5.5	$V_{cc} \times 0.7$	-	_	$V_{cc} \times 0.7$	_	V
Low - Level	.,			2.0	_	_	0.50	_	0.50	.,
Input Voltage	V <sub>IL</sub>		3.0~ 5.5	-	-	$V_{cc} \times 0.3$	_	$V_{cc} \times 0.3$	V	
High - Level Output Voltage	V <sub>OH</sub>	V <sub>I N</sub> =	$I_{OH} = -50\mu A$	2.0	1.9	2.0	_	1.9	-	
				3.0 4.5	2.9 4.4	3.0 4.5	_	2.9 4.4	_	V
		V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0 4.5	2.58 3.94	_	_	2.48 3.80		
Low - Level Output Voltage	V <sub>OL</sub>	V <sub>I N</sub> =	I <sub>OL</sub> = 50μA	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1	_	0.1 0.1 0.1	V
		$V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 4mA I <sub>OL</sub> = 8mA	3.0 4.5		— — —	0.36 0.36	_ _ _	0.14 0.44 0.44	·
Input Leakage Current	I <sub>IN</sub>	$V_{1N} = 5.5V \text{ or } G$	0~5.5	_	_	±0.1	_	± 1.0		
Quiescent Supply Current	I <sub>cc</sub>	$V_{IN} = V_{CC}$ or GN	5.5	_	_	4.0	_	40.0	$\mu$ A	

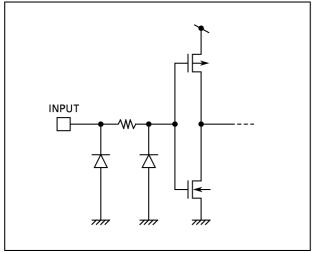
# AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$ )

PARAMETER	SYMBOL	TEST CONDITION		ON	Ta = 25°C		C	Ta = - 4	UNIT	
PARAIVIETER	STIVIBUL		V <sub>CC</sub> (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	UINIT
	t <sub>pLH</sub> t <sub>pHL</sub>	3.3 ± 0.3 5.0 ± 0.5	3.3 ± 0.3	15	_	7.2	11.0	1.0	13.0	
Propagation Delay Time (A,B - $\overline{Y}$ )				50	_	9.7	14.5	1.0	16.5	
			15	_	5.0	7.2	1.0	8.5		
			3.0 ± 0.3	50	_	6.5	9.2	1.0	10.5	ns
	t <sub>pLH</sub> t <sub>pHL</sub>		3.3 ± 0.3	15	_	6.4	9.2	1.0	11.0	
Propagation Delay Time $(\overline{G} - \overline{Y})$				50	_	8.9	12.7	1.0	14.5	
			5.0 ± 0.5	15	_	4.4	6.3	1.0	7.5	
				50	_	5.9	8.3	1.0	9.5	
Input Capacitance	C <sub>I N</sub>				_	4	10	_	10	, הר
Power Dissipation Capacitance	C <sub>PD</sub>		(Note 1)		_	26	_	_	_	pF

Note (1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

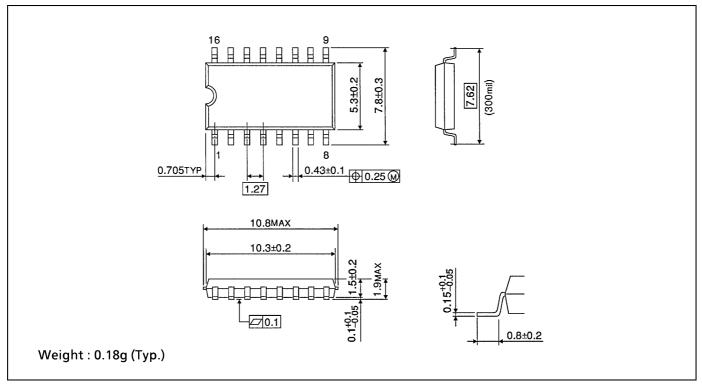
Average operating current can be obtained by the equation:  $I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$  (per decoder)

# INPUT EQUIVALENT CIRCUIT



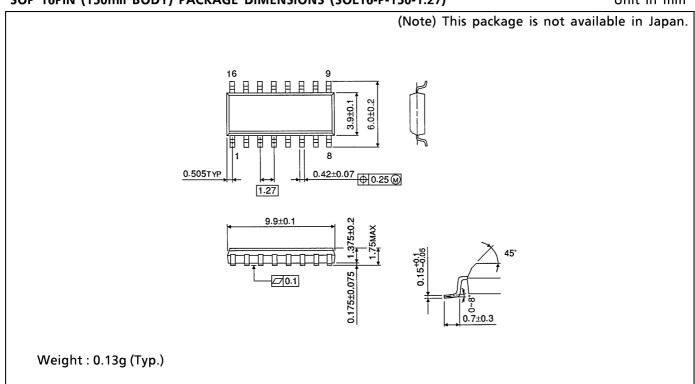
# SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm



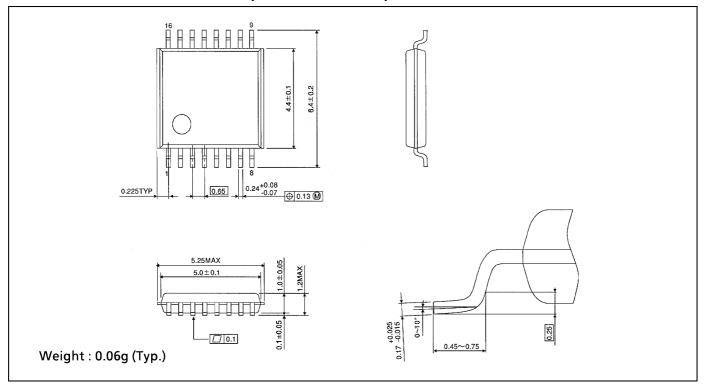
#### SOP 16PIN (150mil BODY) PACKAGE DIMENSIONS (SOL16-P-150-1.27)

Unit in mm



# TSSOP 16PIN PACKAGE DIMENSIONS (TSSOP16-P-0044-0.65)

Unit in mm



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